

# MBT35200MT1, SMBT35200MT1G

## High Current Surface Mount PNP Silicon Switching Transistor for Load Management in Portable Applications

### Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-35	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-55	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	-2.0	Adc
Collector Current - Peak	I <sub>CM</sub>	-5.0	A
Electrostatic Discharge	ESD	HBM Class 3 MM Class C	

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 1)	625 5.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 1)	200	°C/W
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 2)	1.0 8.0	W mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 2)	120	°C/W
Thermal Resistance, Junction-to-Lead #1	R <sub>θJL</sub>	80	°C/W
Total Device Dissipation (Single Pulse < 10 sec.)	P <sub>Dsingle</sub> (Notes 2 & 3)	1.75	W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 X 1.0 inch Pad
3. ref: Figure 9

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



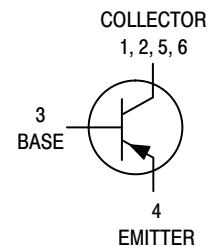
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<http://onsemi.com>

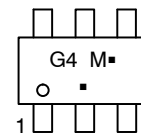
**35 VOLTS  
2.0 AMPS  
PNP TRANSISTOR**



**CASE 318G  
TSOP-6  
STYLE 6**



### MARKING DIAGRAM



G4 = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping†
MBT35200MT1	TSOP-6	3,000 / Tape & Reel
MBT35200MT1G	TSOP-6 (Pb-Free)	3,000 / Tape & Reel
SMBT35200MT1G	TSOP-6 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

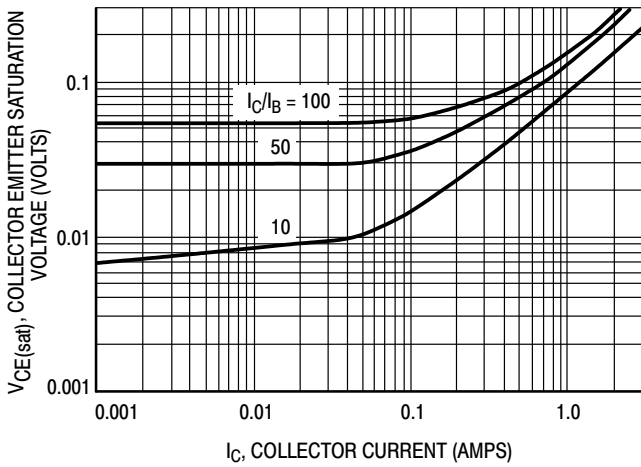
# MBT35200MT1, SMBT35200MT1G

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

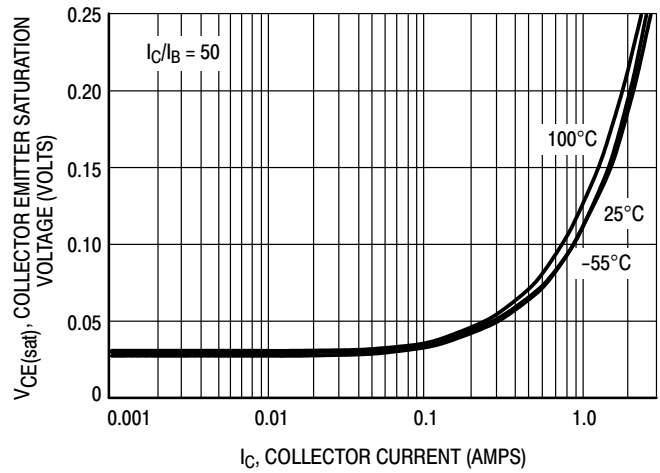
Characteristic	Symbol	Min	Typical	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	-35	-45	-	Vdc
Collector – Base Breakdown Voltage (I <sub>C</sub> = -0.1 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	-55	-65	-	Vdc
Emitter – Base Breakdown Voltage (I <sub>E</sub> = -0.1 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	-5.0	-7.0	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -35 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-0.03	-0.1	μAdc
Collector – Emitter Cutoff Current (V <sub>CE</sub> = -35 Vdc)	I <sub>CES</sub>	-	-0.03	-0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = -4.0 Vdc)	I <sub>EBO</sub>	-	-0.01	-0.1	μAdc
<b>ON CHARACTERISTICS</b>					
DC Current Gain (Note 1) (I <sub>C</sub> = -1.0 A, V <sub>CE</sub> = -1.5 V) (I <sub>C</sub> = -1.5 A, V <sub>CE</sub> = -1.5 V) (I <sub>C</sub> = -2.0 A, V <sub>CE</sub> = -3.0 V)	h <sub>FE</sub>	100 100 100	200 200 200	- 400 -	
Collector – Emitter Saturation Voltage (Note 1) (I <sub>C</sub> = -0.8 A, I <sub>B</sub> = -0.008 A) (I <sub>C</sub> = -1.2 A, I <sub>B</sub> = -0.012 A) (I <sub>C</sub> = -2.0 A, I <sub>B</sub> = -0.02 A)	V <sub>CE(sat)</sub>	- - -	-0.125 -0.175 -0.260	-0.15 -0.20 -0.31	V
Base – Emitter Saturation Voltage (Note 1) (I <sub>C</sub> = -1.2 A, I <sub>B</sub> = -0.012 A)	V <sub>BE(sat)</sub>	-	-0.68	-0.85	V
Base – Emitter Turn-on Voltage (Note 1) (I <sub>C</sub> = -2.0 A, V <sub>CE</sub> = -3.0 V)	V <sub>BE(on)</sub>	-	-0.81	-0.875	V
Cutoff Frequency (I <sub>C</sub> = -100 mA, V <sub>CE</sub> = -5.0 V, f = 100 MHz)	f <sub>T</sub>	100	-	-	MHz
Input Capacitance (V <sub>EB</sub> = -0.5 V, f = 1.0 MHz)	C <sub>ibo</sub>	-	600	650	pF
Output Capacitance (V <sub>CB</sub> = -3.0 V, f = 1.0 MHz)	C <sub>obo</sub>	-	85	100	pF
Turn-on Time (V <sub>CC</sub> = -10 V, I <sub>B1</sub> = -100 mA, I <sub>C</sub> = -1 A, R <sub>L</sub> = 3 Ω)	t <sub>on</sub>	-	35	-	nS
Turn-off Time (V <sub>CC</sub> = -10 V, I <sub>B1</sub> = I <sub>B2</sub> = -100 mA, I <sub>C</sub> = 1 A, R <sub>L</sub> = 3 Ω)	t <sub>off</sub>	-	225	-	nS

1. Pulsed Condition: Pulse Width = 300 μsec, Duty Cycle ≤ 2%

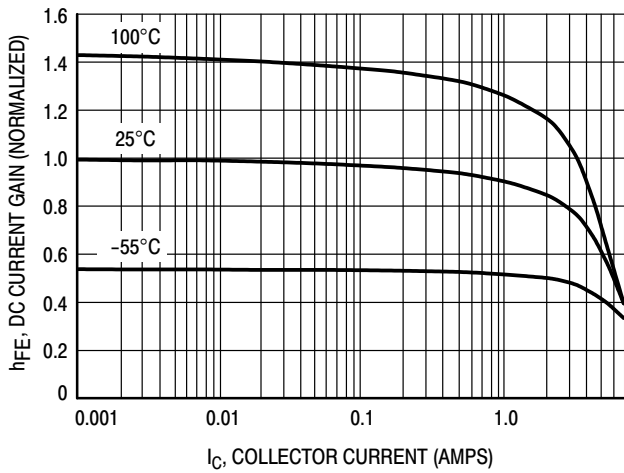
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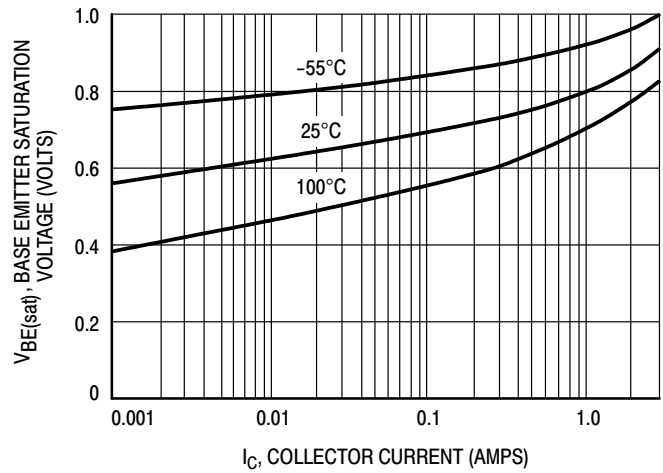
**Figure 1. Collector Emitter Saturation Voltage versus Collector Current**



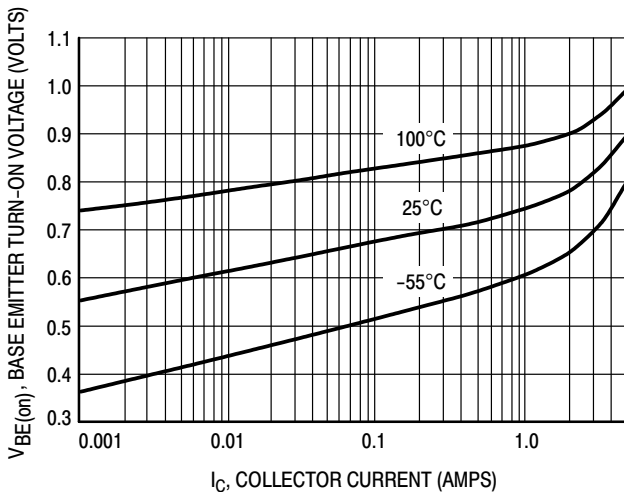
**Figure 2. Collector Emitter Saturation Voltage versus Collector Current**



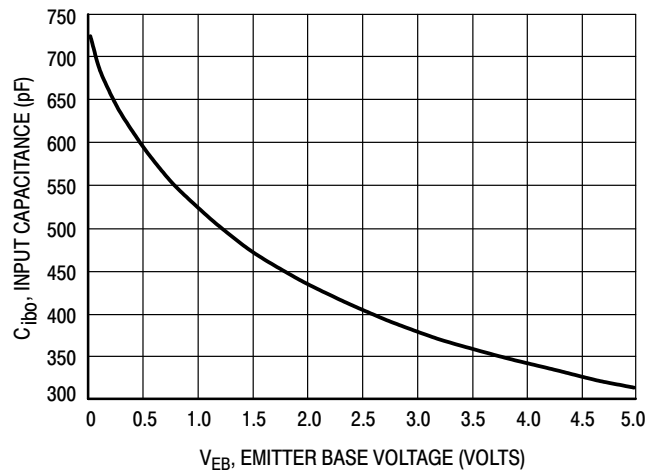
**Figure 3. DC Current Gain versus Collector Current**



**Figure 4. Base Emitter Saturation Voltage versus Collector Current**



**Figure 5. Base Emitter Turn-On Voltage versus Collector Current**



**Figure 6. Input Capacitance**

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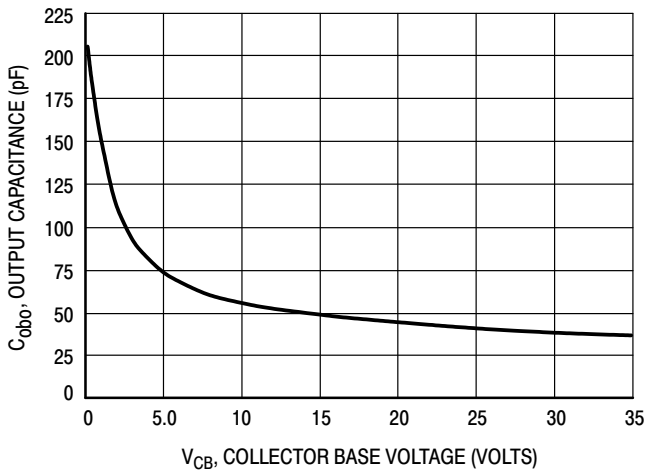


Figure 7. Output Capacitance

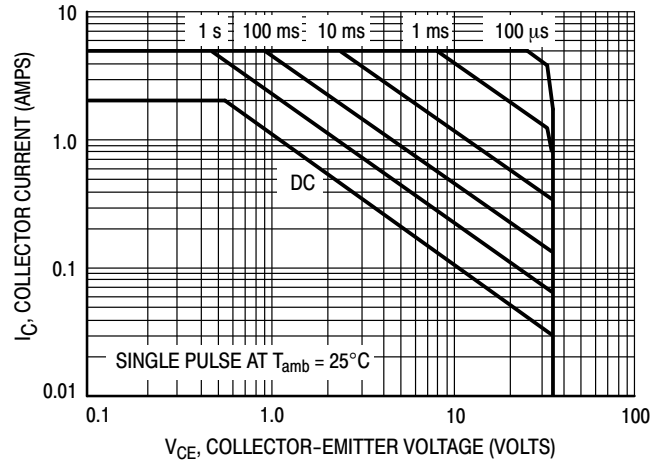


Figure 8. Safe Operating Area

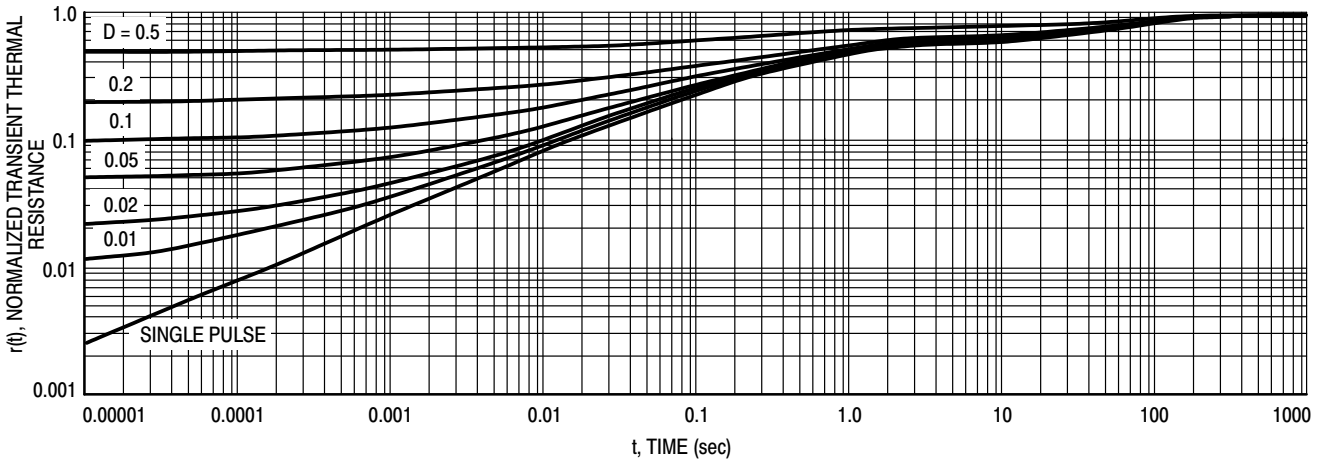
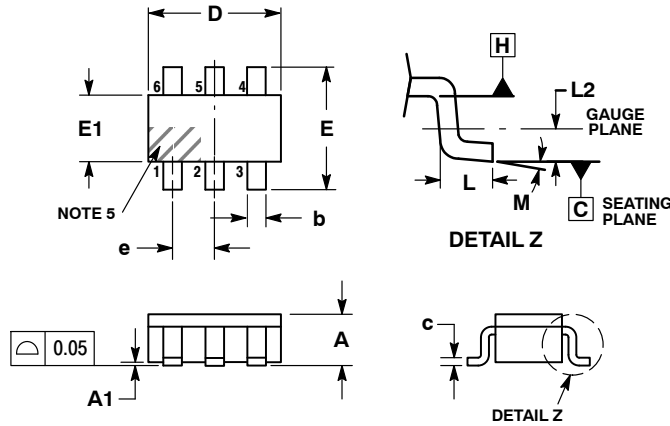


Figure 9. Normalized Thermal Response

# MBT35200MT1, SMBT35200MT1G

## PACKAGE DIMENSIONS

TSOP-6  
CASE 318G-02  
ISSUE U



NOTES:

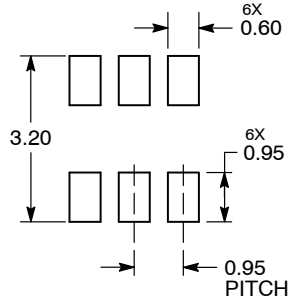
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.01	0.06	0.10
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.90	3.00	3.10
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
M	0°	-	10°

STYLE 6:

1. COLLECTOR
2. COLLECTOR
3. BASE
4. EMITTER
5. COLLECTOR
6. COLLECTOR

### RECOMMENDED SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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